

FDMA86151L Single N-Channel PowerTrench[®] MOSFET

100 V, 3.3 A, 88 mΩ

Features

- Max r_{DS(on)} = 88 mΩ at V_{GS} = 10 V, I_D = 3.3 A
- Max r_{DS(on)} = 132 mΩ at V_{GS} = 4.5 V, I_D = 2.7 A
- Low Profile 0.8 mm maximum in the new package MicroFET 2x2 mm
- Free from halogenated compounds and antimony oxides
- RoHS Compliant

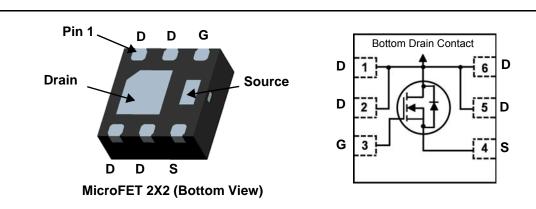


General Description

This device has been designed to provide maximum efficiency and thermal performance for synchronous buck converters. The low rDS(on) and gate charge provide excellent switching performance.

Application

■ DC – DC Buck Converters



MOSFET Maximum Ratings $T_A = 25 \ ^{\circ}C$ unless otherwise noted

Symbol	Parameter			Ratings	Units
V _{DS}	Drain to Source Voltage			100	V
V _{GS}	Gate to Source Voltage			±20	V
1	Drain Curre -Continuous	T _A = 25 °C	(Note 1a)	3.3	^
D	-Pulsed		(Note 3)	20	— A
D	Power Dissipation	T _A = 25 °C	(Note 1a)	2.4	14/
P _D	Power Dissipation	T _A = 25 °C	(Note 1b)	0.9	W
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C

Thermal Characteristics

R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1a)	52	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1b)	145	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
151	FDMA86151L	MicroFET 2X2	7 "	8 mm	3000 units

September 2014

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	octeristics						
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	100			V	
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = 250 µA, referenced to 25 °C		69		mV/°C	
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 80 V, V _{GS} = 0 V			1	μA	
I _{GSS}	Gate to Source Leakage Current	V_{GS} = ±20 V, V_{DS} = 0 V			100	nA	
On Chara	cteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	1.0	2.0	3.0	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-6		mV/°C	
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 3.3 A		60	88		
		V_{GS} = 4.5 V, I _D = 2.7 A		83	132	mΩ	
		V_{GS} = 10 V, I _D = 3.3 A, T _J = 125 °C		102	150	11132	
9 _{FS}	Forward Transconductance	V _{DD} = 5 V, I _D = 3.3 A		8.6		S	
Dynamic	Characteristics						
C _{iss}	Input Capacitance			322	450	pF	
C _{oss}	Output Capacitance	— V _{DS} = 50 V, V _{GS} = 0 V, — f = 1 MHz		55	80	pF	
C _{rss}	Reverse Transfer Capacitance			3	5	pF	
R _g	Gate Resistance		0.1	1.9	3.8	Ω	
Switching	g Characteristics						
t _{d(on)}	Turn-On Delay Time			5.6	12	ns	
t _r	Rise Time	$V_{DD} = 50V, I_D = 3.3 A,$		1.4	10	ns	
t _{d(off)}	Turn-Off Delay Time	— V _{GS} = 10 V, R _{GEN} = 6 Ω		11	20	ns	
t _f	Fall Time			1.6	10	ns	
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 V$ to 10 V		5.2	7.3	nC	
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 V \text{ to } 4.5 V V_{DD} = 50 V,$		2.6	3.7	nC	
Q _{gs}	Gate to Source Charge	I _D = 3.3 A		1.1		nC	
Q _{qd}	Gate to Drain "Miller" Charge			1.0		nC	

Drain-Source Diode Characteristics

V_{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 3.3 A$ (Note 2)	0.8	1.2	V
t _{rr}	Reverse Recovery Time	- I _F = 3.3 A, di/dt = 100 A/μs	33	53	ns
Q _{rr}	Reverse Recovery Charge	$-1_{\rm F} = 5.5$ Å, di/dt = 100 Å/µS	25	40	nC

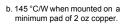
NOTES

 $1. R_{0,J}$ is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{0,JC}$ is guaranteed by design while $R_{0,JA}$ is determined by the user's board design.



3. Pulsed Id limited by junction temperature, td<=10 µS, please refer to SOA curve for more details.

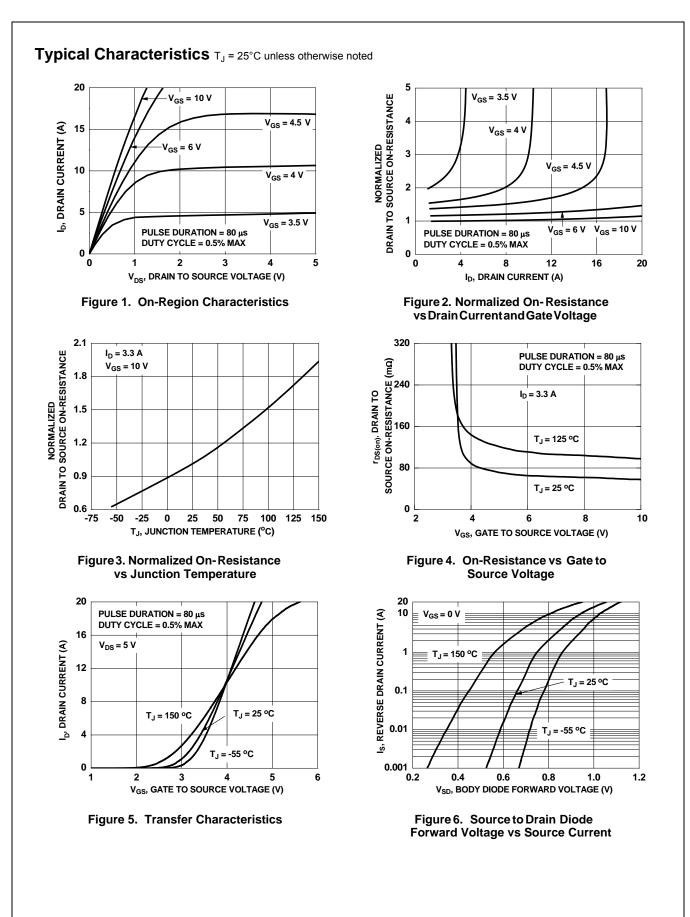




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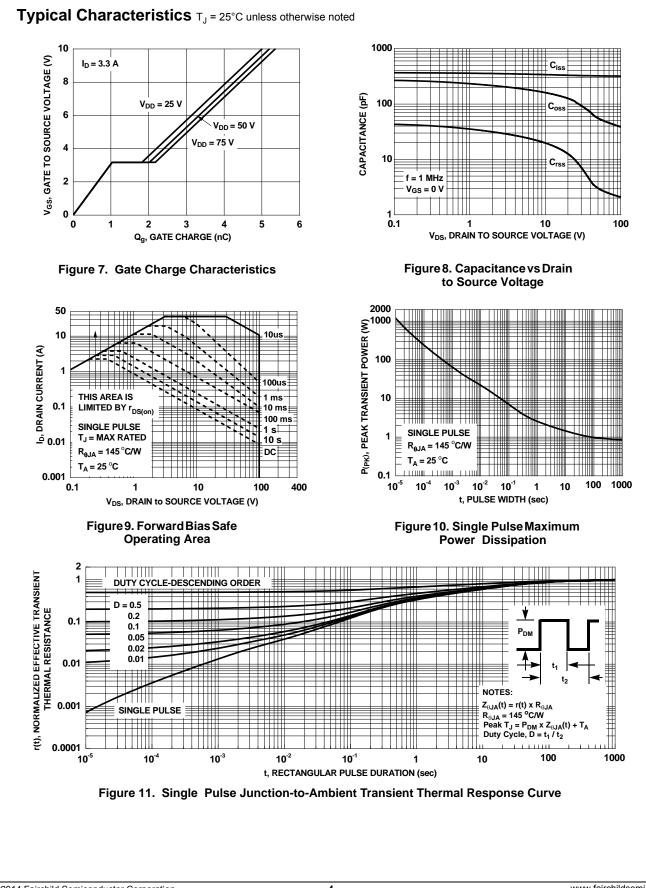
2. Pulse Test: Pulse Width < 300 µs, Duty cycle < 2.0%.

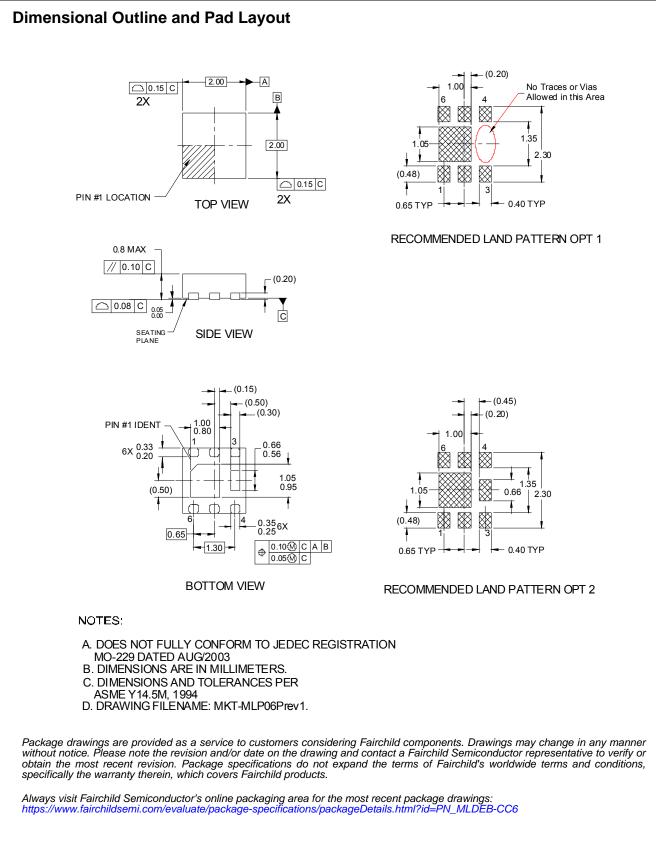
DS

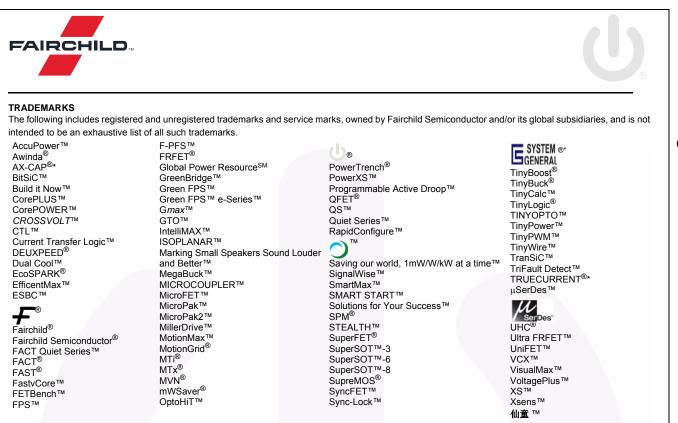


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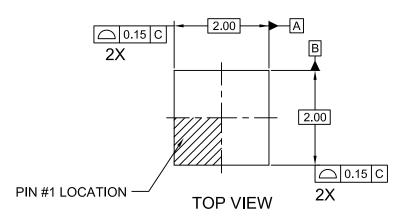
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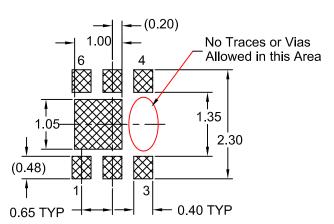
PRODUCT STATUS DEFINITIONS

Definition of Terms

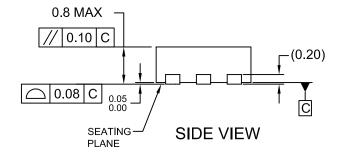
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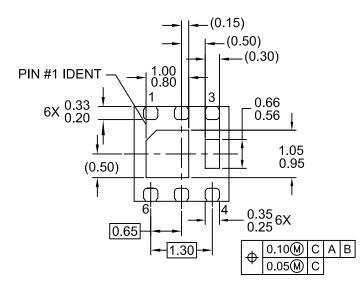
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RECOMMENDED LAND PATTERN OPT 1

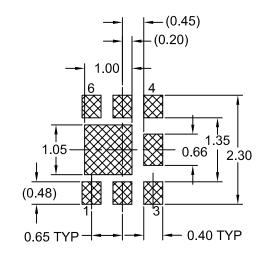




BOTTOM VIEW

NOTES:

- A. DOES NOT FULLY CONFORM TO JEDEC REGISTRATION MO-229 DATED AUG/2003
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994
- D. DRAWING FILENAME: MKT-MLP06Prev1.



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